COMPLIANT

Vishay Siliconix

# 0.37 $\Omega$ , Low Capacitance, Dual DPDT / Quad SPDT Analog Switch

### **DESCRIPTION**

The DG2788A, is a four-channel single-pole double-throw (SPDT) analog switch with two control inputs. It is also known as a two-channel double-pole double-throw (DPDT) configuration. The part is designed to operate from 1.8 V to 5.5 V single power rail. All switches conduct equally well in both directions, offering rail to rail signal switching and can be used both as multiplexers as well as de-multiplexers.

The DG2788A offers low parasitic capacitance and highly matched low and flat switch resistance over the full signal range. It features break-before-make switching and low control logic threshold. The part supports rail to rail fast edge pulsing signals and have 0.1 ns/typ. propagation delay. It is ideal for both analog and digital signal switching in space constrain applications requiring high performance and efficient use of board space.

The DG2788A comes in a small miniQFN-16 lead package of 2.6 mm x 1.8 mm x 0.55 mm.

### **FEATURES**

- 1.8 V to 5.5 V single supply operation
- Low resistance: 0.37 Ω/typ. at 2.7 V
- Highly flat and matched R<sub>ON</sub>
- Low parasitic capacitance,
   C<sub>ON</sub> = 26 pF, C<sub>OFF</sub> = 14.5 pF
- High bandwidth: 338 MHz
- 0.1 ns/typ. propagation delay for rail to rail fast edge pulsing signal
- Guaranteed logic high 1.2 V, logic low 0.3 V
- Break before make switching
- Signal swing over V+ capable
- Power down protection
- Latch up current: 300 mA (JESD78)
- ESD / HBM: > 2 kV
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

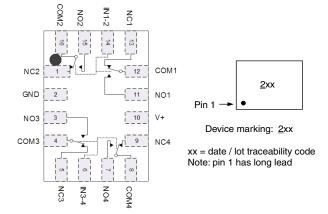
### **BENEFITS**

- Low and flat resistance
- · Excellent total harmonic distortion
- · Low parasitic capacitance
- Low voltage control interface

### **APPLICATIONS**

- · Analog and digital signal switching
- SMA optical image stabilization
- Relay replacement
- Portable instrumentation
- Smart phones and tablets
- · Modems and peripherals
- · Data storage

### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



TRUTH TABLE					
LOGIC	NC1, 2, 3 and 4	NO1, 2, 3 and 4			
0	On	Off			
1	Off	On			



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ORDERING INFORMATION						
TEMPERATURE RANGE	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY			
-40 °C to +85 °C lead (Pb)-free	miniQFN-16	DG2788ADN-T1-GE4	Tape and reel, 3000 units			

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Reference to GND	V+		-0.3 to +6	V		
	IN, COM, NC, NO a		-0.3 to (V+ + 0.3)			
Current (any terminal except NO, NC, or	COM)		30			
Continuous current (NO, NC, or COM)			± 300	mA		
Peak current (pulsed at 1 ms, 10 % duty	cycle)		± 500			
Storage temperature (D suffix)			-65 to +150			
Package solder reflow conditions <sup>d</sup>	miniQFN-16		250	°C		
Power dissipation (packages) <sup>b</sup>	miniQFN-16 <sup>c</sup>		525	mW		

#### **Notes**

- a. Signals on NC, NO, or COM, or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board
- c. Derate 6.6 mW/°C above 70 °C
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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SPECIFICATIONS (V+ = 3 V)								
PARAMETER	SYMBOL	TEST CONDITIONS unless otherwise specified	TEMP.a	<b>LIMITS</b> -40 °C to +85 °C			UNIT	
		$V+ = 3 V, \pm 10 \%, V_{IN} = 0.5 \text{ or } 1.4 \text{ V} ^{\text{e}}$		MIN. b	TYP. °	MAX. b	· · · · ·	
Analog Switch								
Analog signal range <sup>d</sup>	$V_{NO}, V_{NC}, V_{COM}$		Full	0	-	V+	V	
On-resistance	R <sub>ON</sub>	$V+ = 2.7 \text{ V}, V_{COM} = 0 \text{ to } 2.7 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room	-	0.37	0.5		
			Full	-	-	0.6	Ω	
R <sub>ON</sub> flatness <sup>d</sup>	R <sub>ON</sub> flatness	$V+ = 2.7 \text{ V}, V_{COM} = 0 \text{ to } V+,$ $I_{NO}, I_{NC} = 100 \text{ mA}$	Room	-	0.01	0.05		
R <sub>ON</sub> match <sup>d</sup>	$\Delta R_{ON}$	INO, INC = 100 IIIA	Room	-	0.05	-		
	I <sub>NO(off)</sub> ,		Room	-0.1	-	0.1		
Switch off leakage current	I <sub>NC(off)</sub>	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = 0.5 \text{ V} / 4 \text{ V},$	Full	-0.5	-	0.5		
		$V_{COM} = 4 \text{ V} / 0.5 \text{ V}$	Room	-1.2	-	1.2		
	I <sub>COM(off)</sub>		Full	-2	-	2	μA	
Channel-on leakage		V 55VV V V 05V/4V	Room	-1.2	-	1.2	i	
current	I <sub>COM(on)</sub>	$V+ = 5.5 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.5 \text{ V} / 4 \text{ V}$	Full	-2	-	2		
Digital Control								
Input high voltage	V <sub>INH</sub>		Full	1.2	-	-		
Input low voltage	V <sub>INL</sub>		Full	-	-	0.3	V	
Input capacitance	C <sub>IN</sub>		Full	-	5	-	pF	
Input current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 or V+	Full	-1	-	1	μA	
Dynamic Characteristics								
<b>-</b>	t <sub>ON</sub>		Room	-	30	50	μs	
Turn-on time			Full	-	-	150		
T ""		$V_{NO}$ or $V_{NC} = 1.5 \text{ V}$ , $R_L = 50 \Omega$ , $C_L = 35 \text{ pF}$	Room	-	0.35	1		
Turn-off time	t <sub>OFF</sub>		Full	-	-	3		
Break-before-make time	t <sub>d</sub>		Full	1	-	-		
Charge injection d	Q <sub>INJ</sub>	$C_L = 1 \text{ nF}, V_{GEN} = 1.5 \text{ V}, R_{GEN} = 0 \Omega$	Room	-	-245	-	рС	
-3 dB bandwidth	BW	$R_L = 50 \Omega$ , $C_L = 5 pF$	Room	-	338	-	MHz	
		$R_L = 50 \Omega, C_L = 5 pF, f = 100 kHz$		-	-82	-	dB	
Off-isolation d	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$		-	-56	-		
	X <sub>TALK</sub>	$R_L = 50 \Omega, C_L = 5 pF, f = 100 kHz$	Room	_	-87	-		
Crosstalk d, f		$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$		_	-61	-		
Total harmonic distortion and noise	THD+N	$R_L = 50 \Omega, 1 V_{p-p}, f = 1 \text{ kHz}$	Room	-	-104.1	-	dB	
	C <sub>NO(off)</sub>		Room	-	14.5	-		
NO, NC off capacitance <sup>d</sup> Channel-on capacitance <sup>d</sup>	C <sub>NC(off)</sub>	, ,	Room	-	14.5	-	pF	
	C <sub>NO(on)</sub>	f = 1 MHz	Room	-	26	-		
	C <sub>NC(on)</sub>		Room	-	26	-		
Power Supply	110(01)			<u> </u>		<u> </u>		
Power supply range	V+			1.8	_	5.5	V	
Power supply current	I+	V <sub>IN</sub> = 0 or V+	Full	-	24	60	μA	
	• •	- IIV 3 51 1 1		<u> </u>		- •	r., ,	

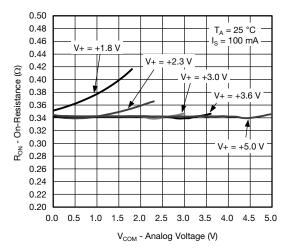
#### Notes

- a. Room = 25 °C, full = as determined by the operating suffix
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet
- c. Typical values are for design aid only, not guaranteed nor subject to production testing
- d. Guarantee by design, not subjected to production test
- e. V<sub>IN</sub> = input voltage to perform proper function
- f. Crosstalk measured between channels

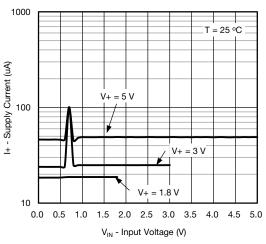
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



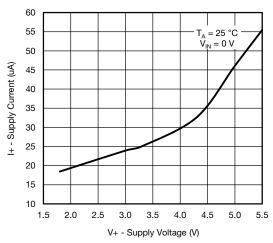
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



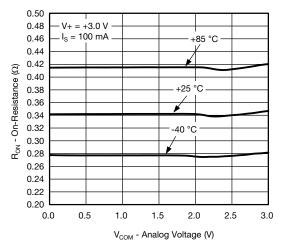
R<sub>ON</sub> vs. V<sub>COM</sub> and Supply Voltage



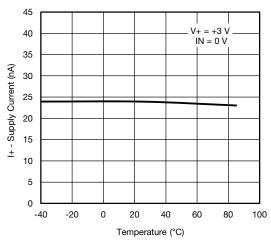
Supply Current vs. Input Voltage



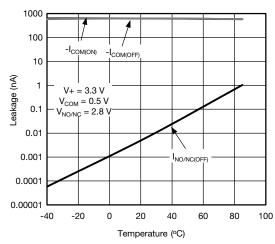
Supply Current vs. Supply Voltage



R<sub>ON</sub> vs. Analog Voltage and Temperature



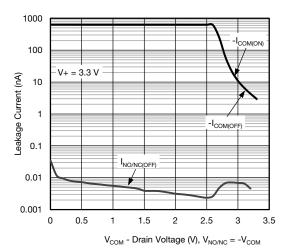
Supply Current vs. Temperature



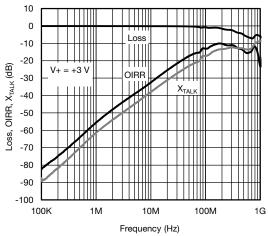
Leakage Current vs. Temperature



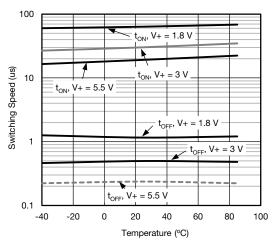
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



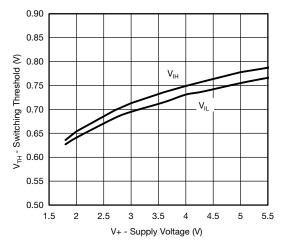
Leakage Current vs. Drain Voltage



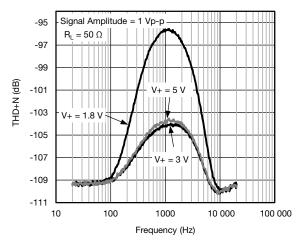
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



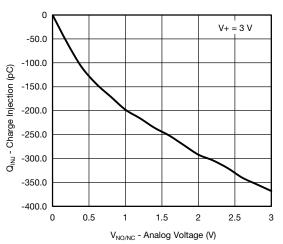
Switching Time vs. Temperature



Switching Threshold vs. Supply Voltage



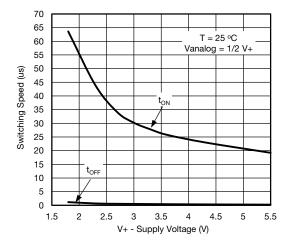
**Total Harmonic Distortion and Noise vs. Frequency** 



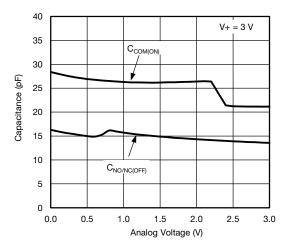
Charge Injection vs. Analog Voltage



## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

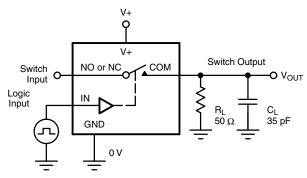


Switching Time vs. Supply Voltage



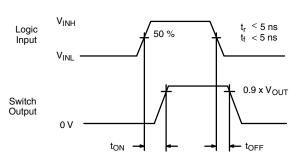
Capacitance vs. Analog Voltage

## **TEST CIRCUITS**



C<sub>L</sub> (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left( \frac{R_L}{R_L + R_{ON}} \right)$$



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Fig. 1 - Switching Time

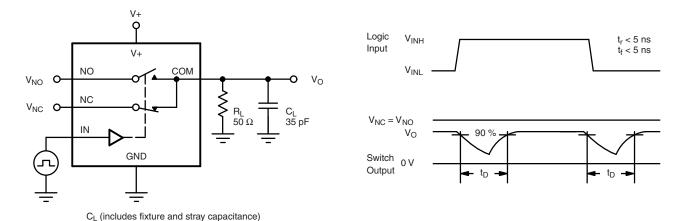
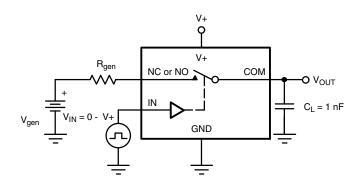
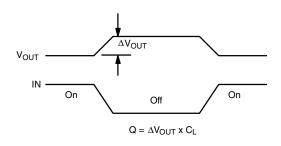


Fig. 2 - Break-Before-Make Interval

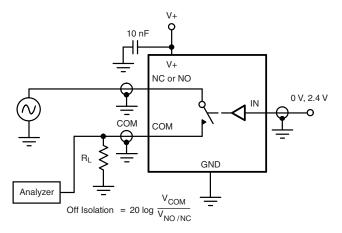






IN depends on switch configuration: input polarity determined by sense of switch.

Fig. 3 - Charge Injection





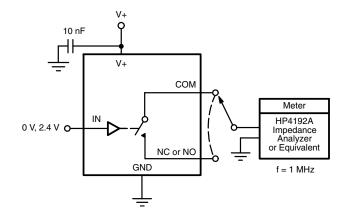
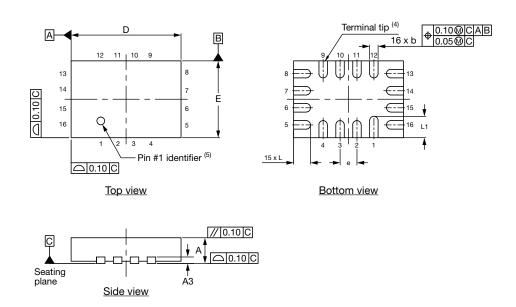


Fig. 5 - Channel Off / On Capacitance

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## Thin miniQFN16 Case Outline



DIMENSIONS	MILLIMETERS (1)			INCHES			
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	0.50	0.55	0.60	0.020	0.022	0.024	
A1	0	-	0.05	0	-	0.002	
A3	0.15 ref.				0.006 ref.		
b	0.15	0.20	0.25	0.006	0.008	0.010	
D	2.50	2.60	2.70	0.098	0.102	0.106	
е	0.40 BSC			0.016 BSC			
Е	1.70	1.80	1.90	0.067	0.071	0.075	
L	0.35	0.40	0.45	0.014	0.016	0.018	
L1	0.45	0.50	0.55	0.018	0.020	0.022	
N (3)	16			16			
Nd <sup>(3)</sup>	4			4			
Ne <sup>(3)</sup>	4 4						

#### Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

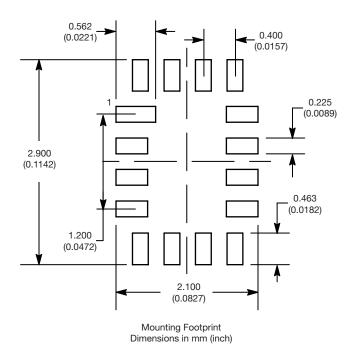
ECN: T16-0226-Rev. B, 09-May-16

DWG: 6023



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## **RECOMMENDED MINIMUM PADS FOR MINI QFN 16L**





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